NSN 5962-01-238-6838



Memory Microcircuit - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5962-01-238-6838 **Body Length:** 1.290 inches **Body Width:** 0.600 inches **Body Height:** 0.200 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** +0.0/+70.0 degrees celsius Storage Tempurature Range: -65.0/+125.0 degrees celsius **Features Provided:** Electrostatic sensitive and ultraviolet erasable and programmable and w/enable and w/buffered output **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 14 input **Terminal Surface Treatment:** Gold **Voltage Rating And Type Per Characteristic:** 26.5 volts power source **Time Rating Per Chacteristic:** 450.00 nanoseconds propagation delay time, low to high level output and 450.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Precious Material And Location:** Terminal surface option gold **Precious Material:** Gold

Test Data Document:

30003-1272as627 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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